NSN 5961-00-008-6831

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View Online at https://aerobasegroup.com/nsn/5961-00-008-6831 **Inclosure Material:** Metal **Overall Length:** 0.505 inches **Overall Diameter:** 0.544 inches **End Application:** F-14 tomcat aircraft. Velocity pool repairable pieve parts. **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.562 inches **Thread Size:** 0.250 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.0 gate trigger voltage, dc **Current Rating Per Characteristic:** 80.00 milliamperes forward current, total rms preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Weapon system essential **Test Data Document:** 82577-925909 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:**

Unf

Terminal Type And Quantity:

2 tab, solder lug

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Shelf	Lite:
N/a	

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0